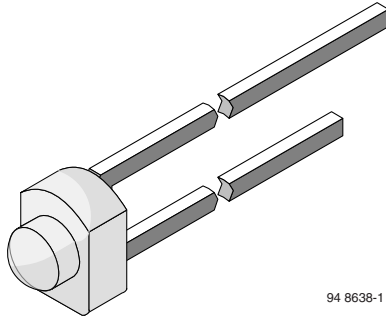




# THE DATASHEET OF BPW17N



## Silicon NPN Phototransistor



94 8638-1

### FEATURES

- Package type: leaded
- Package form: T-3/4
- Dimensions (in mm):  $\varnothing$  1.8
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\varphi = \pm 12^\circ$
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



### Note

\*\* Please see document "Vishay Material Category Policy":  
[www.vishay.com/doc?99902](http://www.vishay.com/doc?99902)

### APPLICATIONS

- Detector in electronic control and drive circuits

### DESCRIPTION

BPW17N is a silicon NPN phototransistor with high radiant sensitivity in clear, T-3/4 plastic package with lens. It is sensitive to visible and near infrared radiation. On PCB this package size enables assembly of arrays with 2.54 mm pitch.

| PRODUCT SUMMARY |               |                 |                      |
|-----------------|---------------|-----------------|----------------------|
| COMPONENT       | $I_{ca}$ (mA) | $\varphi$ (deg) | $\lambda_{0.1}$ (nm) |
| BPW17N          | 1.0           | $\pm 12$        | 450 to 1040          |

### Note

- Test condition see table "Basic Characteristics"

| ORDERING INFORMATION |           |                              |              |
|----------------------|-----------|------------------------------|--------------|
| ORDERING CODE        | PACKAGING | REMARKS                      | PACKAGE FORM |
| BPW17N               | Bulk      | MOQ: 5000 pcs, 5000 pcs/bulk | T-3/4        |

### Note

- MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified) |                                              |            |               |                  |
|---------------------------------------------------------------------------------------|----------------------------------------------|------------|---------------|------------------|
| PARAMETER                                                                             | TEST CONDITION                               | SYMBOL     | VALUE         | UNIT             |
| Collector emitter voltage                                                             |                                              | $V_{CEO}$  | 32            | V                |
| Emitter collector voltage                                                             |                                              | $V_{ECO}$  | 5             | V                |
| Collector current                                                                     |                                              | $I_C$      | 50            | mA               |
| Collector peak current                                                                | $t_p/T = 0.5, t_p \leq 10$ ms                | $I_{CM}$   | 100           | mA               |
| Power dissipation                                                                     | $T_{amb} \leq 55^\circ\text{C}$              | $P_V$      | 100           | mW               |
| Junction temperature                                                                  |                                              | $T_j$      | 100           | $^\circ\text{C}$ |
| Operating temperature range                                                           |                                              | $T_{amb}$  | - 40 to + 100 | $^\circ\text{C}$ |
| Storage temperature range                                                             |                                              | $T_{stg}$  | - 40 to + 100 | $^\circ\text{C}$ |
| Soldering temperature                                                                 | $t \leq 3$ s                                 | $T_{sd}$   | 260           | $^\circ\text{C}$ |
| Thermal resistance junction/ambient                                                   | Connected with Cu wire, 0.14 mm <sup>2</sup> | $R_{thJA}$ | 450           | K/W              |

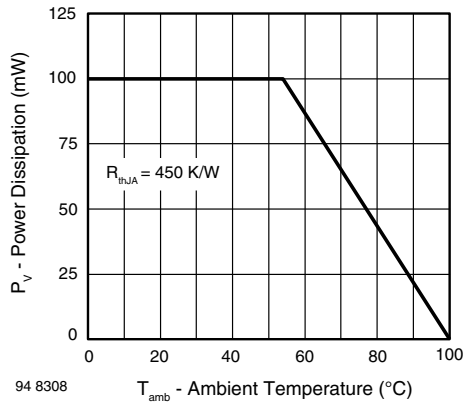


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

| <b>BASIC CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                                                        |                 |      |             |      |               |
|-----------------------------------------------------------------------------------------------------|------------------------------------------------------------------------|-----------------|------|-------------|------|---------------|
| PARAMETER                                                                                           | TEST CONDITION                                                         | SYMBOL          | MIN. | TYP.        | MAX. | UNIT          |
| Collector emitter breakdown voltage                                                                 | $I_C = 1\text{ mA}$                                                    | $V_{(BR)CEO}$   | 32   |             |      | V             |
| Collector emitter dark current                                                                      | $V_{CE} = 20\text{ V}, E = 0$                                          | $I_{CEO}$       |      | 1           | 200  | nA            |
| Collector emitter capacitance                                                                       | $V_{CE} = 5\text{ V}, f = 1\text{ MHz}, E = 0$                         | $C_{CEO}$       |      | 8           |      | pF            |
| Collector light current                                                                             | $E_e = 1\text{ mW/cm}^2, \lambda = 950\text{ nm}, V_{CE} = 5\text{ V}$ | $I_{ca}$        | 0.5  | 1.0         |      | mA            |
| Angle of half sensitivity                                                                           |                                                                        | $\phi$          |      | $\pm 12$    |      | deg           |
| Wavelength of peak sensitivity                                                                      |                                                                        | $\lambda_p$     |      | 825         |      | nm            |
| Range of spectral bandwidth                                                                         |                                                                        | $\lambda_{0.1}$ |      | 450 to 1040 |      | nm            |
| Collector emitter saturation voltage                                                                | $E_e = 1\text{ mW/cm}^2, \lambda = 950\text{ nm}, I_C = 0.1\text{ mA}$ | $V_{CEsat}$     |      |             | 0.3  | V             |
| Turn-on time                                                                                        | $V_S = 5\text{ V}, I_C = 5\text{ mA}, R_L = 100\text{ }\Omega$         | $t_{on}$        |      | 4.8         |      | $\mu\text{s}$ |
| Turn-off time                                                                                       | $V_S = 5\text{ V}, I_C = 5\text{ mA}, R_L = 100\text{ }\Omega$         | $t_{off}$       |      | 5.0         |      | $\mu\text{s}$ |
| Cut-off frequency                                                                                   | $V_S = 5\text{ V}, I_C = 5\text{ mA}, R_L = 100\text{ }\Omega$         | $f_c$           |      | 120         |      | kHz           |

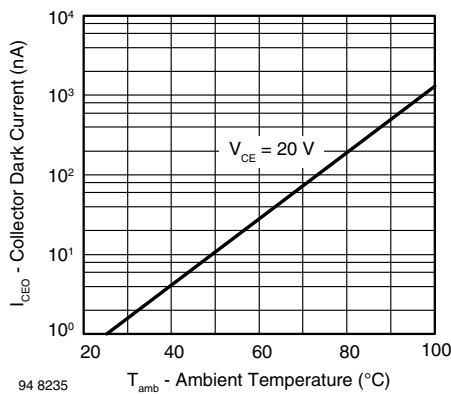
**BASIC CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)


Fig. 1 - Collector Dark Current vs. Ambient Temperature

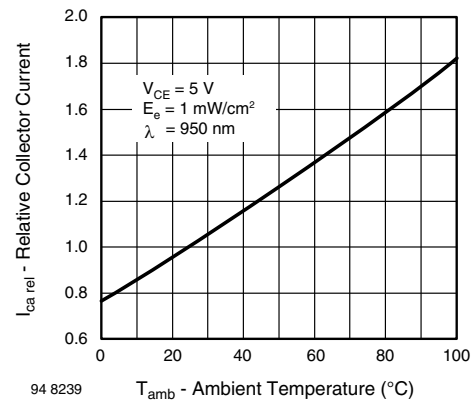


Fig. 2 - Relative Collector Current vs. Ambient Temperature

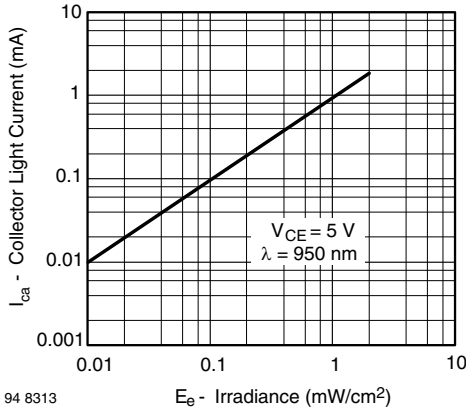


Fig. 3 - Collector Light Current vs. Irradiance

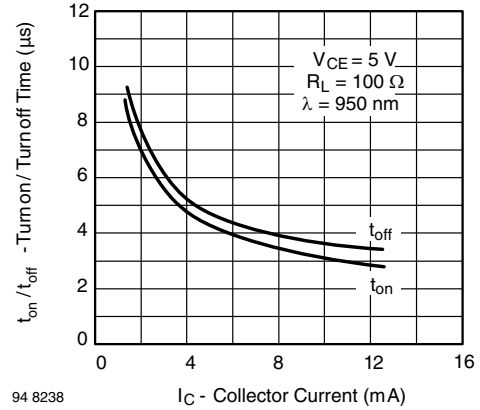


Fig. 6 - Turn-on/Turn-off Time vs. Collector Current

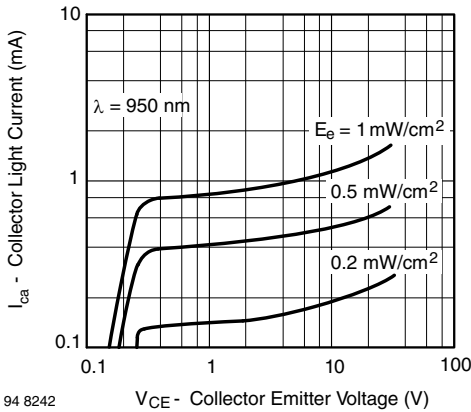


Fig. 4 - Collector Light Current vs. Collector Emitter Voltage

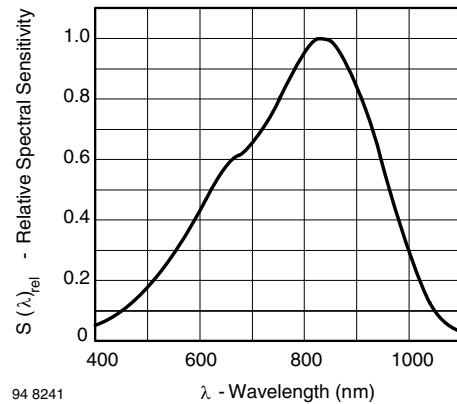


Fig. 7 - Relative Spectral Sensitivity vs. Wavelength

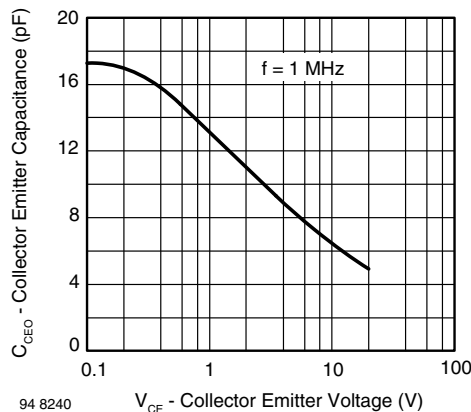


Fig. 5 - Collector Emitter Capacitance vs. Collector Emitter Voltage

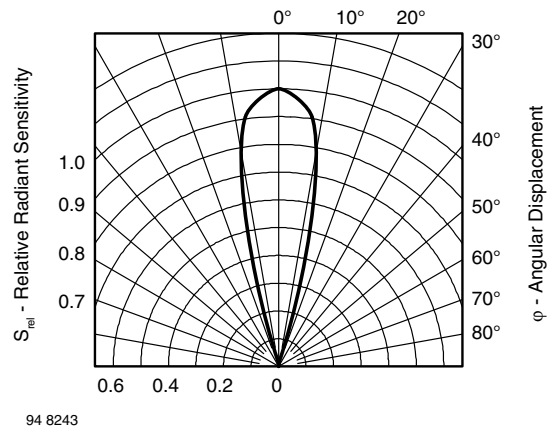
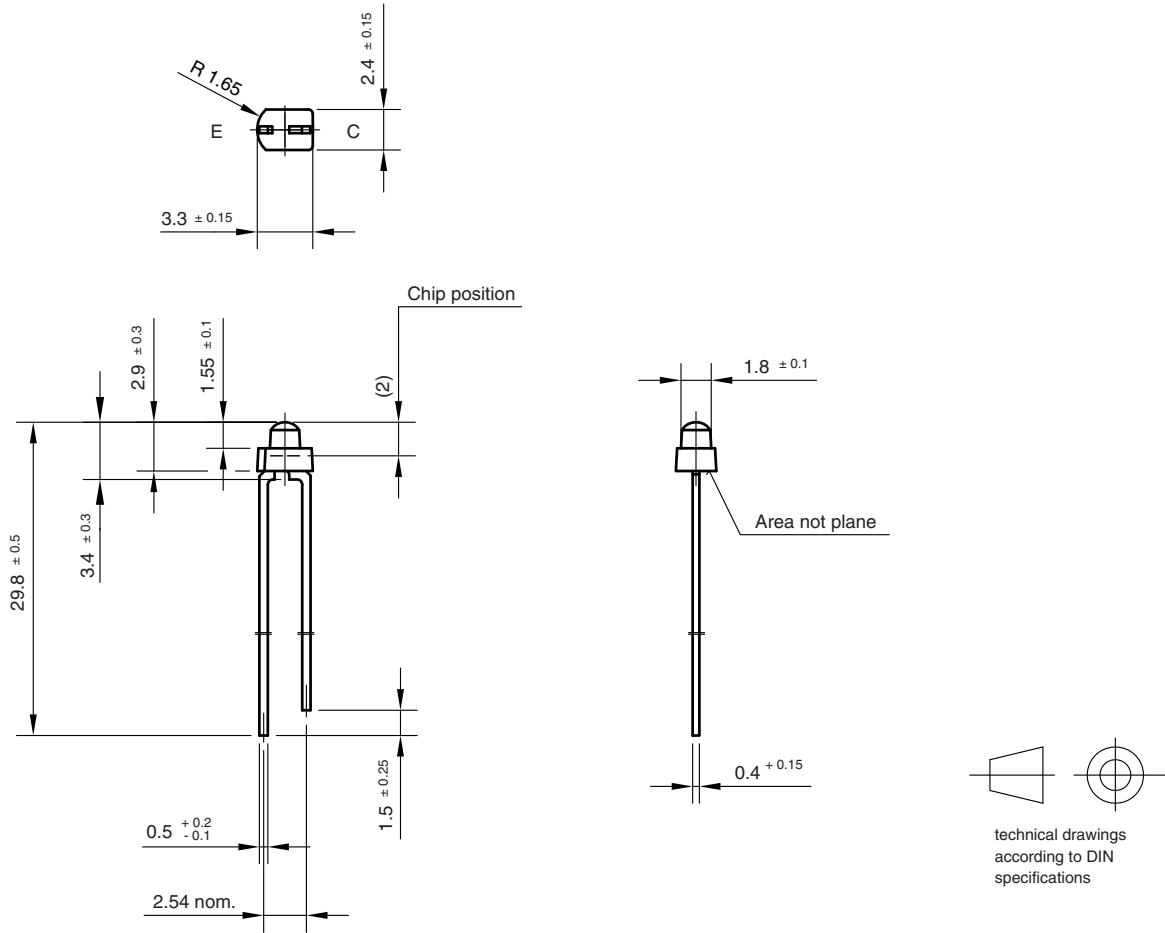


Fig. 8 - Relative Radiant Sensitivity vs. Angular Displacement



PACKAGE DIMENSIONS in millimeters



6.544-5042.01-4  
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